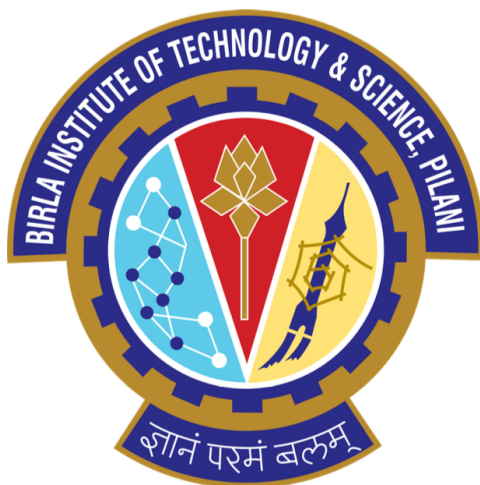


# **Microprocessors and Interfacing Design Assignment for Semester II, 2022-23**

## **Report on Batch Weighing Machine**

In partial fulfillment of the course MICROPROCESSOR PROGRAMMING AND  
INTERFACING



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# Problem Statement

## Batch Weighing Machine

A microprocessor-based system is to be designed as a batch weighing machine.

The system is interfaced to three load cells by means of an 8-bit A/D converter.

The conditioned output of the load cells is given by the equation:  $V_{out} = 0.025 \times \text{weight (Kgs.)}$

The system monitors the output of the load cells and finds out the total weight by taking the average of the three values that are sensed by each load cell.

This value is displayed on a seven-segment display.

When this value exceeds 99 kgs, an output port, which is connected to a relay, is switched on to sound an alarm.

Once the objects are placed on the load cell user presses a switch labelled *weigh*.

# User Requirements and Technical Specifications

- A Batch Weighing machine that measures the weight of an object on 3 different load cells and displays the average weight in kg.
  - A '*weigh*' switch enables the user to begin the weighing.
  - If the average weight crosses 99 kg a buzzer is switched on which can be turned off by a switch.
  - Design has a weight restriction of 100 kg and just 1 decimal precision in weight display.
- Additionally, the procedure only begins when a switch is pressed until the microprocessor is in the polling state, waiting for the interrupt sent by the switch.

## Assumptions

- The weights measured are less than 100 kg and thus load cell with a capacity of 100 kg was used.
- Load cell output through OP-AMP matches the specified 0.02V/kg required by ADC0808 with 5.12V.

## Justifications

- Multiplexing is not used in 7-segment displays to reduce idle CPU consumption. Even though there are only 3 inputs of ADC being used, 8 channel IC was used over 4 channel one to avoid possible implementation errors.
- The ADC resolution in terms of weight is 0.5kg, and with an average of 3 load cells can give a resolution of  $\frac{1}{3}$  kg, which can be represented with just one digit after the decimal.
- Using remainder during division (in average), it is possible to avoid using 8087 co-processor for floating point operations since there are only 6 possible remainders which can be compensated in the code.

# Components Used

- **8086**
  - 1 unit
  - It is the main processor and is used to control all the other devices in the system.
- **8254**
  - 1 unit
  - Used to generate a 1 MHz clock for the ADC0808.
- **8284**
  - 1 unit
  - It generates the clock signal for the 8086 and other clock-based devices in the system.
- **8255**
  - 2 units
  - 8255<sub>(1)</sub> is used to interface the ADC which connects the load cell and 8255<sub>(2)</sub> is used to interface the FND 507 7-segment Display and Buzzer.
- **2716 (ROM)**
  - 4 units
  - We need to provide 2 ROMs at each location as one is the even bank while the other is the odd bank.
  - 2 x 2716 at address 00000H for the IVT.
  - 2 x 2716 at address FF000H to supply instructions at the reset address of the 8086.
- **6116 (RAM)**
  - 2 units
  - We need to provide 2 RAMs at each location as one is the even bank while the other is the odd bank.
  - 2 x 6116 is used to store data and stack.
- **LS373**
  - 3 units
  - Used to de-multiplex and latch the Address Bus of the 8086.

- **LS245**
  - 2 units
  - Used to de-multiplex and latch the Data Bus of the 8086.
- **ADC0808**
  - 1 unit
  - Used to convert the analog output of the load cell to digital signals for the microprocessor.
- **Switch**
  - 2 units
  - Used to start the weighing process
  - Used to start the buzzer acknowledge
- **8259**
  - Used it for the interrupts provided by the switch *weigh*, EOC from ADC and stop buzzer switch.
- **7447**
  - 4 units
  - Used to decode the BCD value received from Microprocessors to 7-segment display
- **FND 507**
  - Used to display the calculated weight
- **Buzzer**
  - Used to ring the alarm when the weight exceeds 99 kgs
- **Relay**
  - 2 units
  - This electrically operated switch used to interface with the buzzer
- **Load cells**
  - 3 units
  - Used to calculate the weight and send analog signals to ADC
- **Or gates wherever necessary**



# Address Map

## Memory Map

A <sub>19</sub>	A <sub>18</sub>	A <sub>17</sub>	A <sub>16</sub>	A <sub>15</sub>	A <sub>14</sub>	A <sub>13</sub>	A <sub>12</sub>	A <sub>11</sub>	A <sub>10</sub>	A <sub>9</sub>	A <sub>8</sub>	A <sub>7</sub>	A <sub>6</sub>	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A <sub>0</sub>	Address	Memory
0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	00000 <sub>H</sub>	ROM1
0	0	0	0	0	0	0	0	1	1	1	1	1	1	1	1	1	1	1	1	00FFF <sub>H</sub>	
0	0	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	01000 <sub>H</sub>	RAM1
0	0	0	0	0	0	0	1	1	1	1	1	1	1	1	1	1	1	1	1	01FFF <sub>H</sub>	
1	1	1	1	1	1	1	1	0	0	0	0	0	0	0	0	0	0	0	0	FF000 <sub>H</sub>	ROM2
1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	1	FFFFF <sub>H</sub>	

The highlighted address lines A<sub>14</sub>, A<sub>13</sub> and A<sub>12</sub> can be used to decide the memory.

## I/O Map

A <sub>7</sub>	A <sub>6</sub>	A <sub>5</sub>	A <sub>4</sub>	A <sub>3</sub>	A <sub>2</sub>	A <sub>1</sub>	A <sub>0</sub>	Address	Memory
0	0	1	0	0	0	0	0	20 <sub>H</sub>	8255 <sub>(1)</sub>
0	0	1	0	0	1	1	0	26 <sub>H</sub>	
0	0	1	0	1	0	0	0	28 <sub>H</sub>	8255 <sub>(2)</sub>
0	0	1	0	1	1	1	0	2E <sub>H</sub>	
0	0	1	1	0	0	0	0	30 <sub>H</sub>	8254
0	0	1	1	0	1	1	0	36 <sub>H</sub>	
0	0	1	1	1	0	0	0	38 <sub>H</sub>	8259
0	0	1	1	1	0	1	0	3A <sub>H</sub>	

The highlighted address lines A<sub>5</sub>, A<sub>4</sub> and A<sub>3</sub> can be used to decide the I/O.

## 8255 Ports

### 8255<sub>(1)</sub>

Port	Address	Purpose
Port A	20 <sub>H</sub>	Unused
Port B	22 <sub>H</sub>	Interfaces the ADC Outputs (D <sub>0</sub> -D <sub>7</sub> of the ADC) to the data bus of 8086
Port C	24 <sub>H</sub>	Interfaces the ADC Inputs (Control signals - ALE, SOC, OE and AD <sub>0</sub> -AD <sub>2</sub> )
Control Register	26 <sub>H</sub>	Used to initialise 8255 <sub>(1)</sub> ports

### 8255<sub>(2)</sub>

Port	Address	Purpose
Port A	28 <sub>H</sub>	Interfaces the BCD input of 7447
Port B	2A <sub>H</sub>	Interfaces the BCD input of 7447
Port C	2C <sub>H</sub>	C0 is interfaced to set Buzzer On
Control Register	2E <sub>H</sub>	Used to initialise 8255 <sub>(2)</sub> ports

# Load cell

The load cell is a transducer that converts a force such as tension, compression, pressure, or torque into an electrical signal that can be measured and standardized. A load cell is made up of four strain gauges arranged in a Wheatstone pattern.

The load cell used is INDUSTRIAL GRADE LOAD CELL BEAM TYPE 100 KG WEIGHT SENSOR STRAIGHT BAR

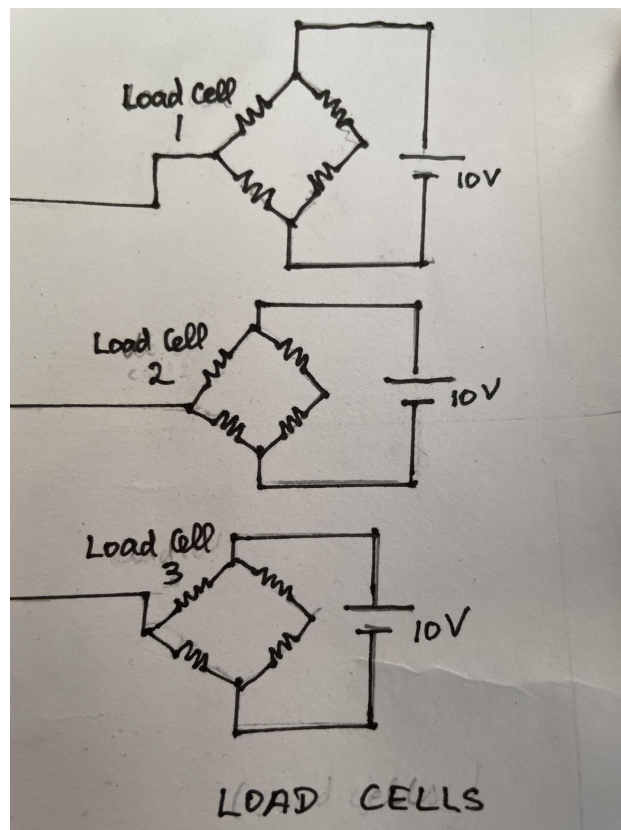
## Specifications :

Capacity: 100 kg

Rated output(MV/V):  $2.0 \pm 0.15$

Output voltage of cells = rated output \* excitation value

Output voltage of cells =  $2(\text{mv/v}) * 10 = 20 \text{ mV}$



## Working of the design

The load cell is used to measure the weight and send the signal to the amplifier to amplify the signal and thus send to the 8-bit ADC.

We have a load cell with sensitivity of 2mv/v thus if the input is V voltage then the output is  $k*W*V$  where W is weight.  $V_{ref+}$  for the ADC is taken as 5.12 V and  $V_{ref-}$  is grounded.

As ADC is 8-bit resolution, we need to measure about 100 kg and the closest power of 2 is 128 so  $256/128 = 2$  units/kg which is 0.04 v/kg for  $V_{ref} = 5.12$  V. Thus each load cell can measure up to 0.5kg resolution with LSB of ADC.

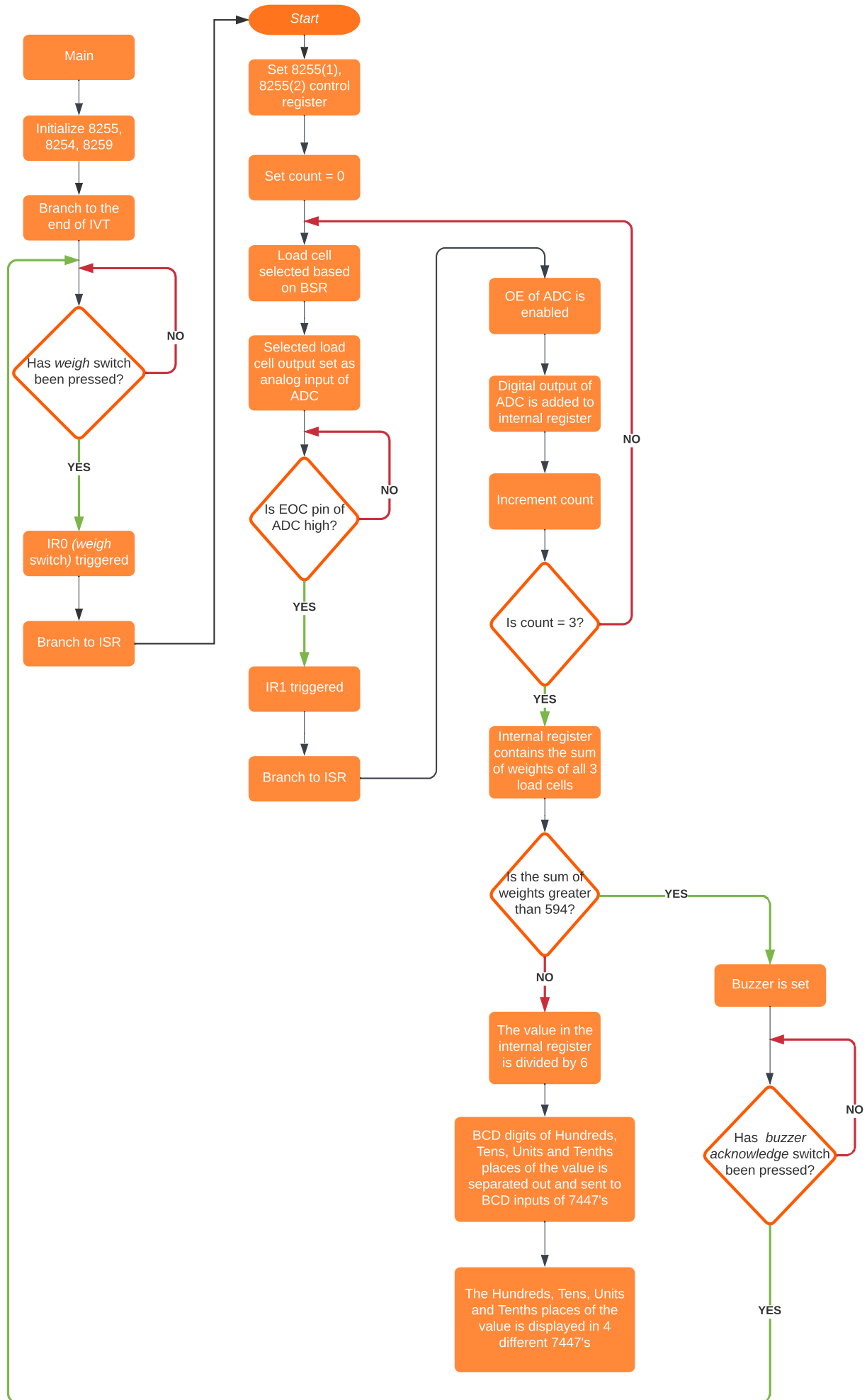
$$0.04 = k*v* A \quad (A \text{ is Amplifier gain})$$

1 unit is 0.5 kg

As 1 level is 0.5 kg thus an average of three weights  $(W1+W2+W3)/3$  is equivalent to  $(L1+L2+L3)/6$

The calculated weight is displayed using the 7-segment display and if weight is more then 99 kg then buzzer starts to ring.

# Flowchart



# Appendix

## Datasheets and links

1. 8086

<https://pdf1.alldatasheet.com/datasheet-pdf/view/130012/INTEL/8086.html>

2. 8254

<https://pdf1.alldatasheet.com/datasheet-pdf/view/130012/INTEL/8086.html>

3. 8255

<https://pdf1.alldatasheet.com/datasheet-pdf/view/66100/INTEL/8255A.html>

4. 2716 (ROM)

<https://datasheetpdf.com/pdf-file/957635/Intel/2716/1>

5. 6116 (RAM)

<https://datasheetpdf.com/pdf-file/957635/Intel/2716/1>

6. 7447

<https://pdf1.alldatasheet.com/datasheet-pdf/view/82663/ETC/7447.html>

7. FND 507 (7 Segment display)

[https://www.alldatasheet.com/view.jsp?Searchword=Fnd507%20datasheet&gclid=Cj0KCQjwxYoiBhC9ARIsANiElfahYgIhkpCPSZRMoindjyUDsVAhCjatuCIHkW2Llc2fc5yK3odYdBgaAp7IEALw\\_wcB](https://www.alldatasheet.com/view.jsp?Searchword=Fnd507%20datasheet&gclid=Cj0KCQjwxYoiBhC9ARIsANiElfahYgIhkpCPSZRMoindjyUDsVAhCjatuCIHkW2Llc2fc5yK3odYdBgaAp7IEALw_wcB)

8. Relay

<https://pdf1.alldatasheet.com/datasheet-pdf/view/43479/SHARP/S202S01.html>

9. Amplifier

[https://www.ti.com/product/LM741-MIL?utm\\_source=supplyframe&utm\\_medium=SEP&utm\\_campaign=not\\_alldatasheet&DCM=yes&dclid=CMP2m43Guv4CFVE5aAodaSoPVA#params](https://www.ti.com/product/LM741-MIL?utm_source=supplyframe&utm_medium=SEP&utm_campaign=not_alldatasheet&DCM=yes&dclid=CMP2m43Guv4CFVE5aAodaSoPVA#params)

10. Load cell

<https://probots.co.in/load-cell-100-kg-weight-sensor-straight-bar-electronic.html>

11. Buzzer

<https://www.sunrom.com/download/598.pdf>

12. ADC0808

<https://pdf1.alldatasheet.com/datasheet-pdf/download/929603/TI1/ADC0808.html>

## ADC0808/ADC0809 8-Bit $\mu$ P Compatible A/D Converters with 8-Channel Multiplexer

Check for Samples: [ADC0808-N](#), [ADC0809-N](#)

### FEATURES

- Easy Interface to All Microprocessors
- Operates Ratiometrically or with 5 V<sub>DC</sub> or Analog Span Adjusted Voltage Reference
- No Zero or Full-Scale Adjust Required
- 8-Channel Multiplexer with Address Logic
- 0V to V<sub>CC</sub> Input Range
- Outputs meet TTL Voltage Level Specifications
- ADC0808 Equivalent to MM74C949
- ADC0809 Equivalent to MM74C949-1

### KEY SPECIFICATIONS

- Resolution: 8 Bits
- Total Unadjusted Error:  $\pm 1/2$  LSB and  $\pm 1$  LSB
- Single Supply: 5 VDC
- Low Power: 15 mW
- Conversion Time: 100  $\mu$ s

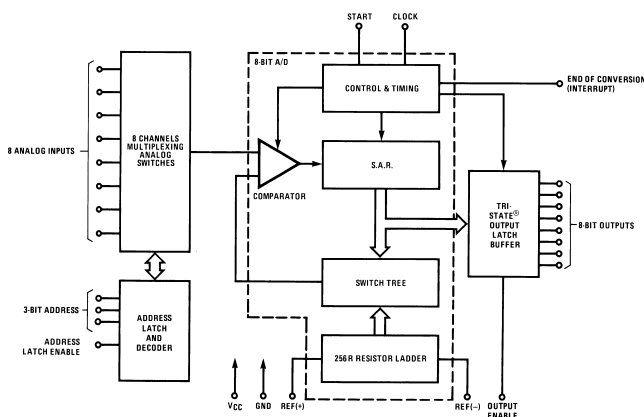
### DESCRIPTION

The ADC0808, ADC0809 data acquisition component is a monolithic CMOS device with an 8-bit analog-to-digital converter, 8-channel multiplexer and microprocessor compatible control logic. The 8-bit A/D converter uses successive approximation as the conversion technique. The converter features a high impedance chopper stabilized comparator, a 256R voltage divider with analog switch tree and a successive approximation register. The 8-channel multiplexer can directly access any of 8-single-ended analog signals.

The device eliminates the need for external zero and full-scale adjustments. Easy interfacing to microprocessors is provided by the latched and decoded multiplexer address inputs and latched TTL TRI-STATE outputs.

The design of the ADC0808, ADC0809 has been optimized by incorporating the most desirable aspects of several A/D conversion techniques. The ADC0808, ADC0809 offers high speed, high accuracy, minimal temperature dependence, excellent long-term accuracy and repeatability, and consumes minimal power. These features make this device ideally suited to applications from process and machine control to consumer and automotive applications. For 16-channel multiplexer with common output (sample/hold port) see ADC0816 data sheet. (See AN-247 (Literature Number [SNOA595](#)) for more information.)

### Block Diagram



### Connection Diagrams

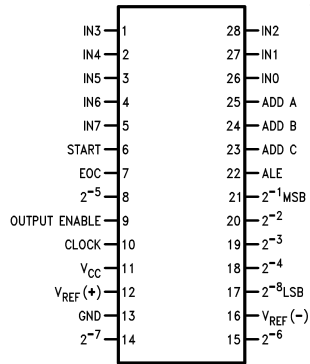


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

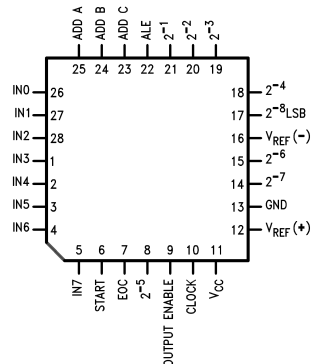
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**Figure 1. PDIP Package**  
See Package N0028E



**Figure 2. PLCC Package**  
See Package FN0028A



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### Absolute Maximum Ratings<sup>(1)(2)(3)</sup>

Supply Voltage ( $V_{CC}$ ) <sup>(4)</sup>		6.5V
Voltage at Any Pin Except Control Inputs		-0.3V to ( $V_{CC}+0.3V$ )
Voltage at Control Inputs (START, OE, CLOCK, ALE, ADD A, ADD B, ADD C)		-0.3V to +15V
Storage Temperature Range		-65°C to +150°C
Package Dissipation at $T_A=25^\circ\text{C}$		875 mW
Lead Temp. (Soldering, 10 seconds)	PDIP Package (plastic)	260°C
	PLCC Package	Vapor Phase (60 seconds)
		Infrared (15 seconds)
ESD Susceptibility <sup>(5)</sup>		400V

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its specified operating conditions.
- (2) All voltages are measured with respect to GND, unless otherwise specified.
- (3) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.
- (4) A Zener diode exists, internally, from  $V_{CC}$  to GND and has a typical breakdown voltage of 7  $V_{DC}$ .
- (5) Human body model, 100 pF discharged through a 1.5 k $\Omega$  resistor.

### Operating Conditions<sup>(1)(2)</sup>

Temperature Range	$T_{MIN} \leq T_A \leq T_{MAX}$ -40°C $\leq T_A \leq$ +85°C
Range of $V_{CC}$	4.5 $V_{DC}$ to 6.0 $V_{DC}$

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its specified operating conditions.
- (2) All voltages are measured with respect to GND, unless otherwise specified.

### Electrical Characteristics – Converter Specifications

**Converter Specifications:**  $V_{CC}=5$   $V_{DC}=V_{REF+}$ ,  $V_{REF(-)}=GND$ ,  $T_{MIN} \leq T_A \leq T_{MAX}$  and  $f_{CLK}=640$  kHz unless otherwise stated.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
	ADC0808	25°C			$\pm\frac{1}{2}$	LSB
	Total Unadjusted Error <sup>(1)</sup>	$T_{MIN}$ to $T_{MAX}$			$\pm\frac{3}{4}$	LSB

- (1) Total unadjusted error includes offset, full-scale, linearity, and multiplexer errors. See Figure 5. None of these A/Ds requires a zero or full-scale adjust. However, if an all zero code is desired for an analog input other than 0.0V, or if a narrow full-scale span exists (for example: 0.5V to 4.5V full-scale) the reference voltages can be adjusted to achieve this. See Figure 15.



Figure 6 shows a typical error curve for the ADC0808.

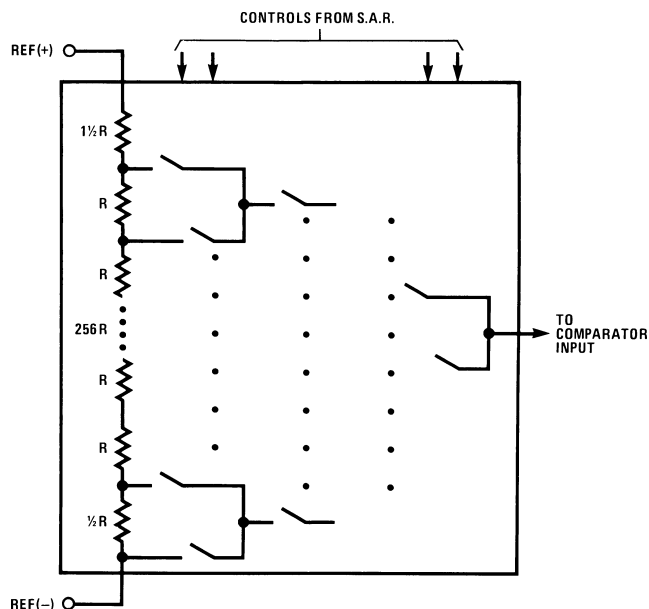


Figure 3. Resistor Ladder and Switch Tree

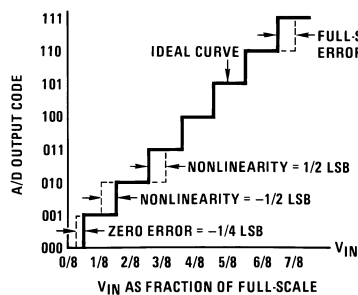


Figure 4. 3-Bit A/D Transfer Curve

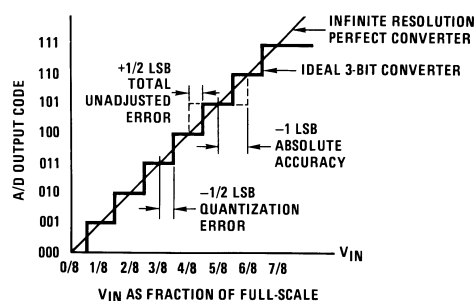


Figure 5. 3-Bit A/D Absolute Accuracy Curve

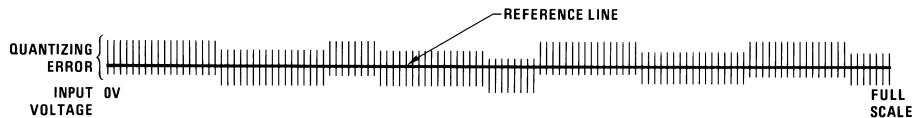
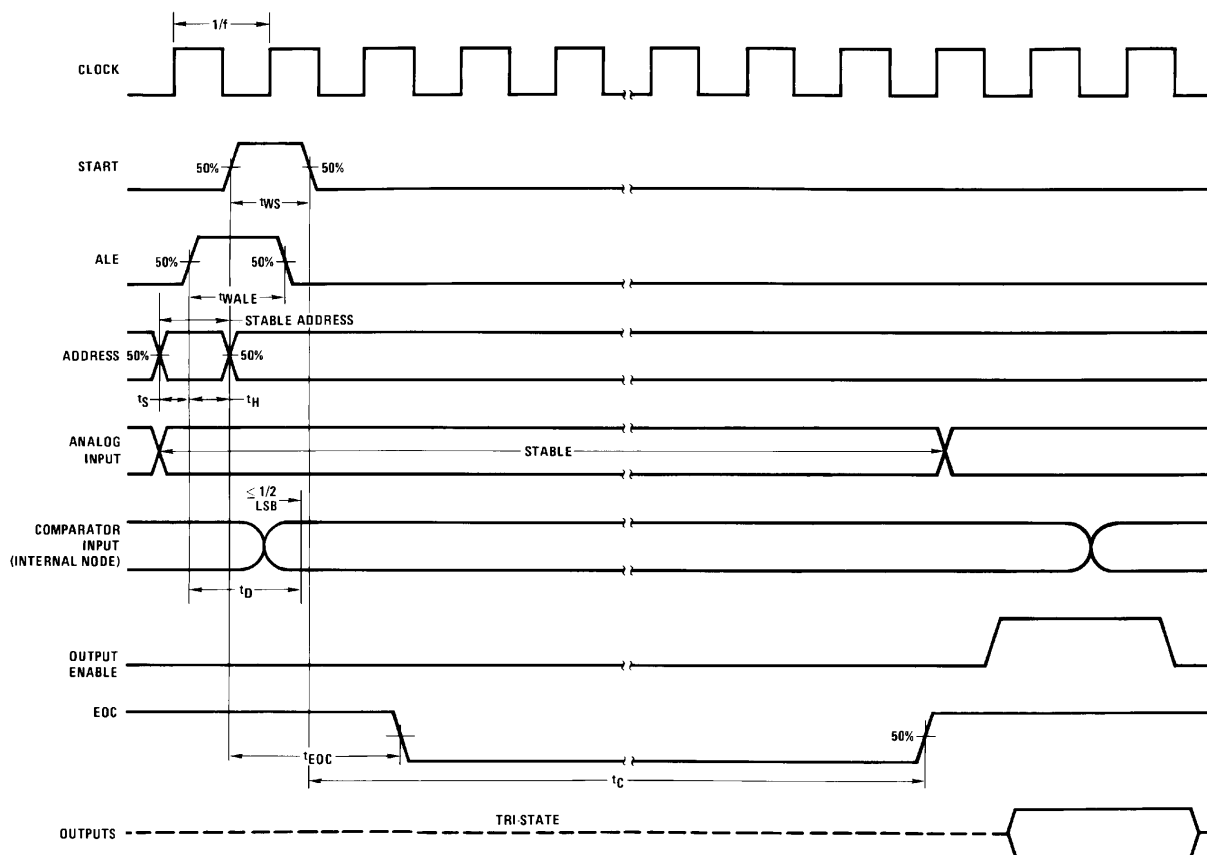


Figure 6. Typical Error Curve

## Timing Diagram



**Figure 7.**

## APPLICATIONS INFORMATION

### OPERATION

#### RATIOMETRIC CONVERSION

The ADC0808, ADC0809 is designed as a complete Data Acquisition System (DAS) for ratiometric conversion systems. In ratiometric systems, the physical variable being measured is expressed as a percentage of full-scale which is not necessarily related to an absolute standard. The voltage input to the ADC0808 is expressed by the equation

$$\frac{V_{IN}}{V_{fs} - V_Z} = \frac{D_X}{D_{MAX} - D_{MIN}}$$

- $V_{IN}$  = Input voltage into the ADC0808
- $V_{fs}$  = Full-scale voltage
- $V_Z$  = Zero voltage
- $D_X$  = Data point being measured
- $D_{MAX}$  = Maximum data limit
- $D_{MIN}$  = Minimum data limit

(1)

A good example of a ratiometric transducer is a potentiometer used as a position sensor. The position of the wiper is directly proportional to the output voltage which is a ratio of the full-scale voltage across it. Since the data is represented as a proportion of full-scale, reference requirements are greatly reduced, eliminating a large source of error and cost for many applications. A major advantage of the ADC0808, ADC0809 is that the input voltage range is equal to the supply range so the transducers can be connected directly across the supply and their outputs connected directly into the multiplexer inputs, (Figure 11).

Ratiometric transducers such as potentiometers, strain gauges, thermistor bridges, pressure transducers, etc., are suitable for measuring proportional relationships; however, many types of measurements must be referred to an absolute standard such as voltage or current. This means a system reference must be used which relates the full-scale voltage to the standard volt. For example, if  $V_{CC} = V_{REF} = 5.12V$ , then the full-scale range is divided into 256 standard steps. The smallest standard step is 1 LSB which is then 20 mV.

#### RESISTOR LADDER LIMITATIONS

The voltages from the resistor ladder are compared to the selected into 8 times in a conversion. These voltages are coupled to the comparator via an analog switch tree which is referenced to the supply. The voltages at the top, center and bottom of the ladder must be controlled to maintain proper operation.

The top of the ladder, Ref(+), should not be more positive than the supply, and the bottom of the ladder, Ref(-), should not be more negative than ground. The center of the ladder voltage must also be near the center of the supply because the analog switch tree changes from N-channel switches to P-channel switches. These limitations are automatically satisfied in ratiometric systems and can be easily met in ground referenced systems.

Figure 12 shows a ground referenced system with a separate supply and reference. In this system, the supply must be trimmed to match the reference voltage. For instance, if a 5.12V is used, the supply should be adjusted to the same voltage within 0.1V.

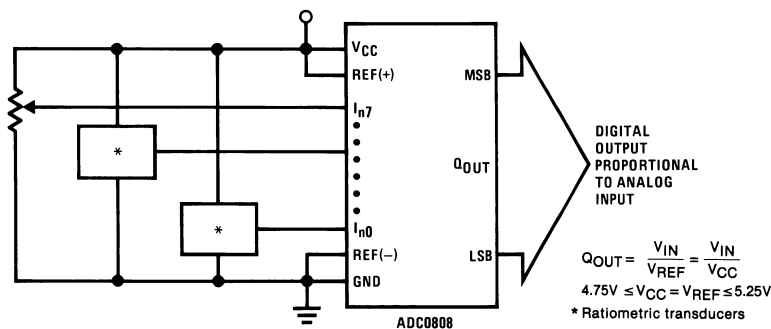


Figure 11. Ratiometric Conversion System

## ANALOG COMPARATOR INPUTS

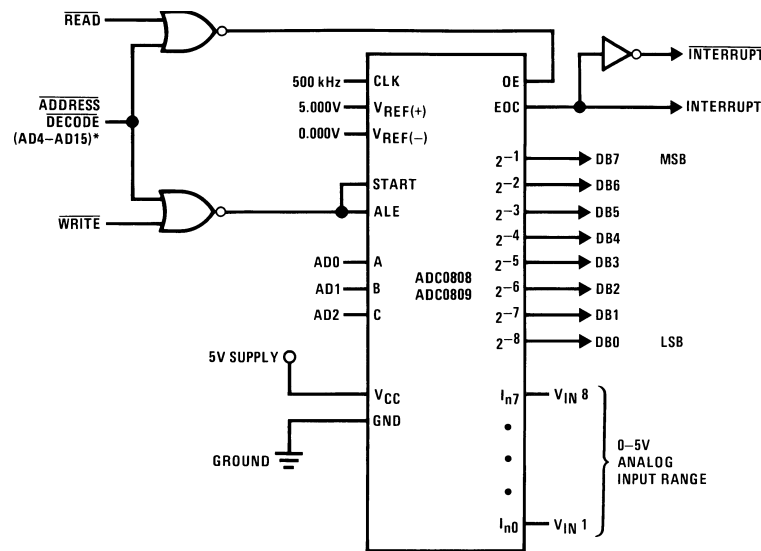
The dynamic comparator input current is caused by the periodic switching of on-chip stray capacitances. These are connected alternately to the output of the resistor ladder/switch tree network and to the comparator input as part of the operation of the chopper stabilized comparator.

The average value of the comparator input current varies directly with clock frequency and with  $V_{IN}$  as shown in Figure 8.

If no filter capacitors are used at the analog inputs and the signal source impedances are low, the comparator input current should not introduce converter errors, as the transient created by the capacitance discharge will die out before the comparator output is strobed.

If input filter capacitors are desired for noise reduction and signal conditioning they will tend to average out the dynamic comparator input current. It will then take on the characteristics of a DC bias current whose effect can be predicted conventionally.

## Typical Application



\*Address latches needed for 8085 and SC/MP interfacing the ADC0808 to a microprocessor

**Table 2. Microprocessor Interface Table**

PROCESSOR	READ	WRITE	INTERRUPT (COMMENT)
8080	$\overline{MEMR}$	$\overline{MEMW}$	INTR (Thru RST Circuit)
8085	$\overline{RD}$	$\overline{WR}$	INTR (Thru RST Circuit)
Z-80	$\overline{RD}$	$\overline{WR}$	$\overline{INT}$ (Thru RST Circuit, Mode 0)
SC/MP	NRDS	NWDS	SA (Thru Sense A)
6800	$VMA \cdot \phi 2 \cdot R/W$	$VMA \cdot \phi \cdot \overline{R/W}$	$\overline{IRQA}$ or $\overline{IRQB}$ (Thru PIA)

# Red GaAsP 0.5-Inch 7-Segment Numeric LED Displays

Optoelectronic Products

## FND500, FND507 FND560, FND567

### General Description

The FND500, FND507, FND560 and FND567 are red GaAsP single-digit 7-Segment LED displays with a 0.5-inch character height. These displays are designed for applications in which the viewer is within twenty feet of the display.

**Low Forward Voltage**—Typically  $V_F = 1.7\text{ V}$   
**Fits Standard DIP Sockets** with 0.6-Inch Pin Row  
**Maximized Contrast Ratio** With Integral Lens Cap  
**Horizontal Stacking** 0.6-Inch Minimum,  
1-Inch Typical

**FND560/567 Suitable For Use in High Ambient Light**

**FND500 Common Cathode, Right-Hand Decimal Point**

**FND507 Common Anode, Right-Hand Decimal Point**

**FND560 Common Cathode, Right-Hand Decimal Point, High Brightness**

**FND567 Common Anode, Right-Hand Decimal Point, High Brightness**

### Absolute Maximum Ratings

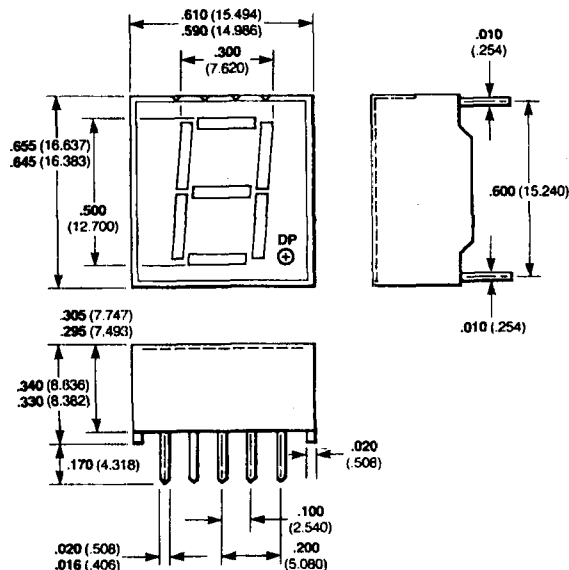
#### Maximum Temperature and Humidity

Storage Temperature	-25°C to +85°C
Operating Temperature	-25°C to +85°C
Pin Temperature (Soldering, 5 s)	260°C
Relative Humidity at 65°C	98%

#### Maximum Voltage and Currents

$V_R$	Reverse Voltage	3.0 V
$I_F$	Average Forward dc Current/Segment or Decimal Point	25 mA
	Derate from 25°C Ambient Temperature	0.3 mA/°C
$I_{pk}$	Peak Forward Current Segment or Decimal Point (100 $\mu$ s pulse width) 1000 pps, $T_A = 25^\circ\text{C}$	200 mA

### Package Outline



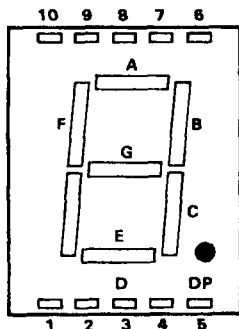
#### Notes

All dimensions in inches bold and millimeters (parentheses)  
Tolerance unless specified =  $\pm .015$  ( $\pm .381$ )

# Connection Diagram Typical Electrical Characteristics

## FND500, FND507 FND560, FND567

### Pin Connections (Front View)



### Pin FND507/567

- 1 Segment E
- 2 Segment D
- 3 Common Anode
- 4 Segment C
- 5 Decimal Point
- 6 Segment B
- 7 Segment A
- 8 Common Anode
- 9 Segment F
- 10 Segment G

### FND500/560

- Segment E
- Segment D
- Common Cathode
- Segment C
- Decimal Point
- Segment B
- Segment A
- Common Cathode
- Segment F
- Segment G

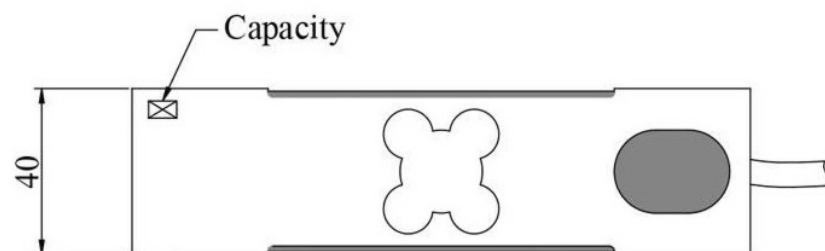
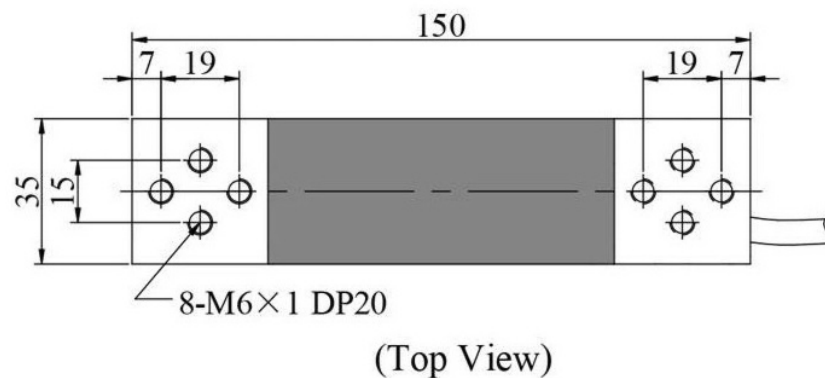
### Electrical and Radiant Characteristics $T_A = 25^\circ\text{C}$

Symbol	Characteristic	Min	Typ	Max	Units	Test Conditions
$V_F$	Forward Voltage	1.5	1.7	2.0	V	$I_F = 20 \text{ mA}$
$BV_R$	Reverse Breakdown Voltage	3.0	12		V	$I_R = 1.0 \text{ mA}$
$I_O$	Axial Luminous Intensity, Average Each-Segment FND500, FND507 FND560, FND567	300 740	600 1200		$\mu\text{cd}$ $\mu\text{cd}$	$I_F = 20 \text{ mA}$ $I_F = 20 \text{ mA}$
$\Delta I_O$	Intensity Matching, Segment-to-Segment Intensity Matching Within One Intensity Class		$\pm 33$ $\pm 20$		% %	$I_F = 20 \text{ mA}$ $I_F = 20 \text{ mA}$ , all segments at once
$L_O$	Average Segment Luminance FND500, FND507 FND560, FND567		35 70		$\text{ftL}$ $\text{ftL}$	$I_F = 20 \text{ mA}$ $I_F = 20 \text{ mA}$
$\theta_{1/2}$	Viewing Angle to Half Intensity		$\pm 27$		degrees	
$\lambda_{pk}$	Peak Wavelength		665		nm	$I_F = 20 \text{ mA}$

# INDUSTRIAL GRADE LOAD CELL BEAM TYPE 100 KG WEIGHT SENSOR STRAIGHT BAR

The load cell is a transducer that converts a force such as tension, compression, pressure, or torque into an electrical signal that can be measured and standardized. These Load cells are designed with high-grade elements and construction materials for good environmental sealing and performance, this suits both Industrial and Commercial applications.

**Size: mm**



## (Front View)



### Details

#### Description:

This Load cell can be used to measure the weight of objects between 0 and 100 kg. This straight bar load cell (sometimes called a strain gauge) can translate up to 100 kg of pressure (force) into an electrical signal. Each load cell is able to measure the electrical resistance that changes in response to and is proportional to, the strain (e.g. pressure or force) applied to the bar. With this gauge, you will be able to tell just how heavy an object is, if an object's weight changes over time, or if you simply need to sense the presence of an object by measuring strain or load applied to a surface.

Each straight bar load cell is made from an aluminum alloy and is capable of reading a capacity of 100 kg. These load cells have four strain gauges that are hooked up in a Wheatstone bridge formation. The color code on the wiring is as follows: red = E+, green = O+, black = E-, and white = O-. Additionally, these load cells feature through holes for mounting purposes.

Use this sensor using our HX711 Breakout Board to amplify its signal and connect it directly to an Arduino/Raspberry pi or any other general-purpose microcontroller.

#### Applications :

- Electronic platform scale
- Digital scale
- Parcel post scale
- Electronic balance

#### Specifications :

- Capacity: 100KG



- Rated output(MV/V):  $2.0 \pm 0.15$
- Accuracy class: C2
- Maximum number of load cell verification intervals(N max): 2000
- Minimum number of load cell verification intervals(Vmin):  $E_{Max}/5000$
- Combined error(%RO):  $< \pm 0.030$
- Creep(%RO/30min): 0.03
- Temperature effect on sensitivity(%RO/°C): 0.0016
- Temperature effect on zero(%RO/°C): 0.003
- Zero balance(%RO): 1.0
- Input resistance(O):  $402 \pm 6$
- Output resistance(O):  $350 \pm 3$
- Insulation resistance(MO<50V>): 5000
- Recommended excitation voltage(V): 10~15
- Compensated temperature range(°C): -10~+40
- Operating temperature range(°C): -35~+80
- Safe overload(%RO): 150
- Ultimate overload(%RO): 200
- Load cell material: Aluminium
- Connecting cable:  $\varnothing 4.2 \times 350 \text{mm}$
- Method of connecting wire: Red(+),Black(-),Green(+),White(-)

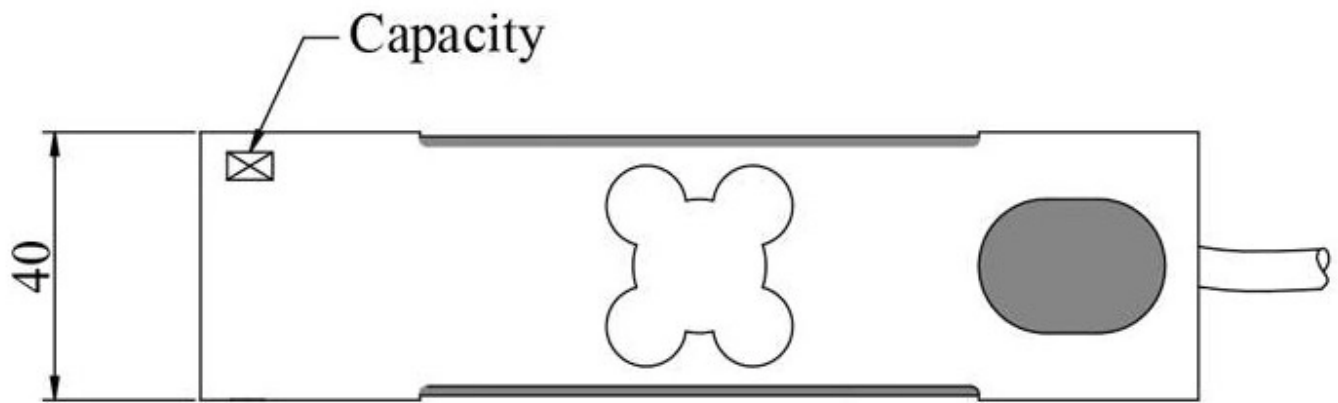
Product Images are shown for illustrative purposes only and may differ from the actual product.

**Size: mm**



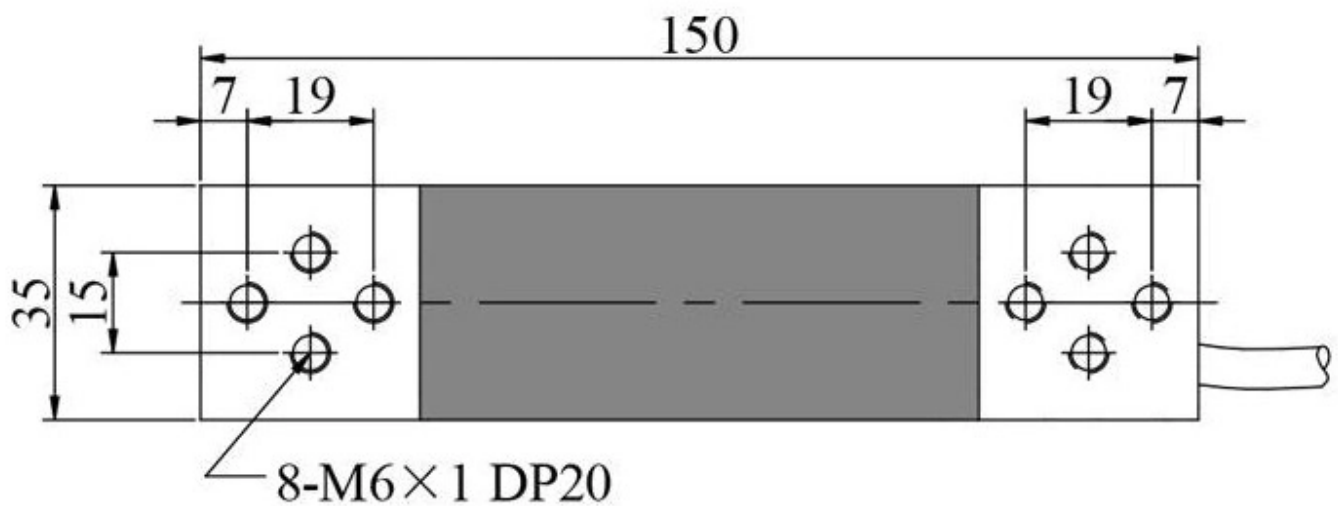


(Top View)

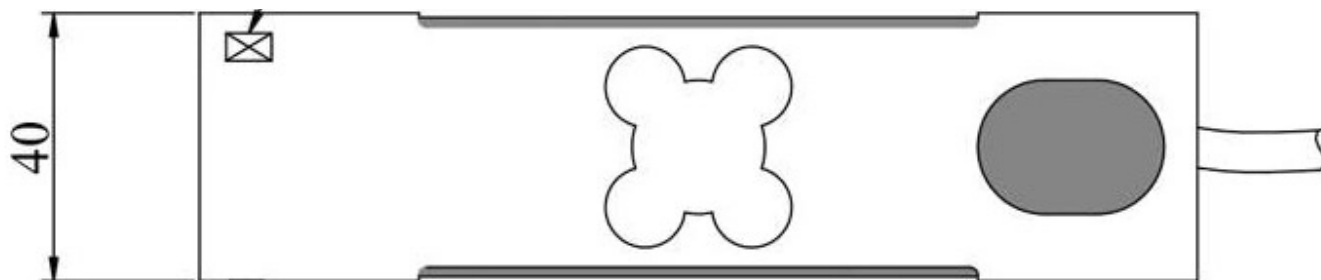


(Front View)

**Size: mm**



(Top View)



(Front View)

More Information



Reviews



Shipping & Delivery



Bulk & B2B Orders



## RELATED PRODUCTS



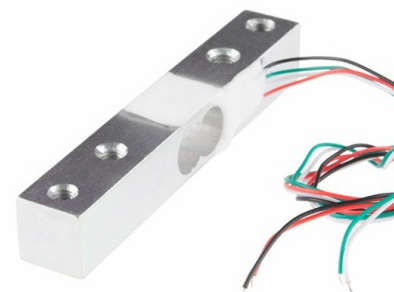
Industrial Grade Load Cell Beam Type  
350 kg Weight Sensor Straight Bar

₹ 999.00



Industrial Grade Load Cell Beam Type  
500 kg Weight Sensor Straight Bar

₹ 999.00



Mini Load Cell Beam Type 1 kg W  
Sensor Straight Bar

₹ 275.00

## LM741-MIL Operational Amplifier

### 1 Features

- Overload Protection on the Input and Output
- No Latch-Up When the Common-Mode Range is Exceeded

### 2 Applications

- Comparators
- Multivibrators
- DC Amplifiers
- Summing Amplifiers
- Integrator or Differentiators
- Active Filters

### 3 Description

The LM741-MIL is a general-purpose operational amplifier which features improved performance over industry standards such as the LM709. It is a direct, plug-in replacement for the 709C, LM201, MC1439, and 748 in most applications.

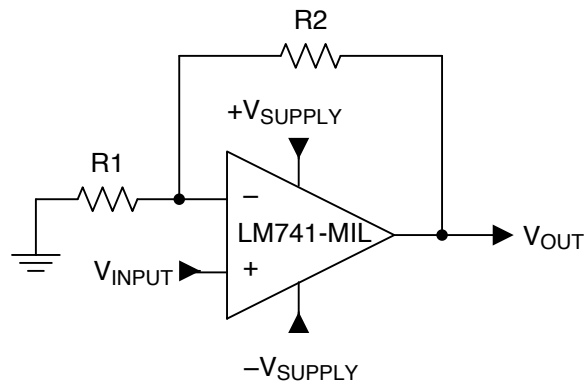
The amplifier offers many features which make applications nearly foolproof such as overload protection on the input and output, no latch-up when the common-mode range is exceeded, and freedom from oscillations.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
LM741-MIL	TO-99 (8)	9.08 mm × 9.08 mm
	CDIP (8)	10.16 mm × 6.502 mm
	PDIP (8)	9.81 mm × 6.35 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

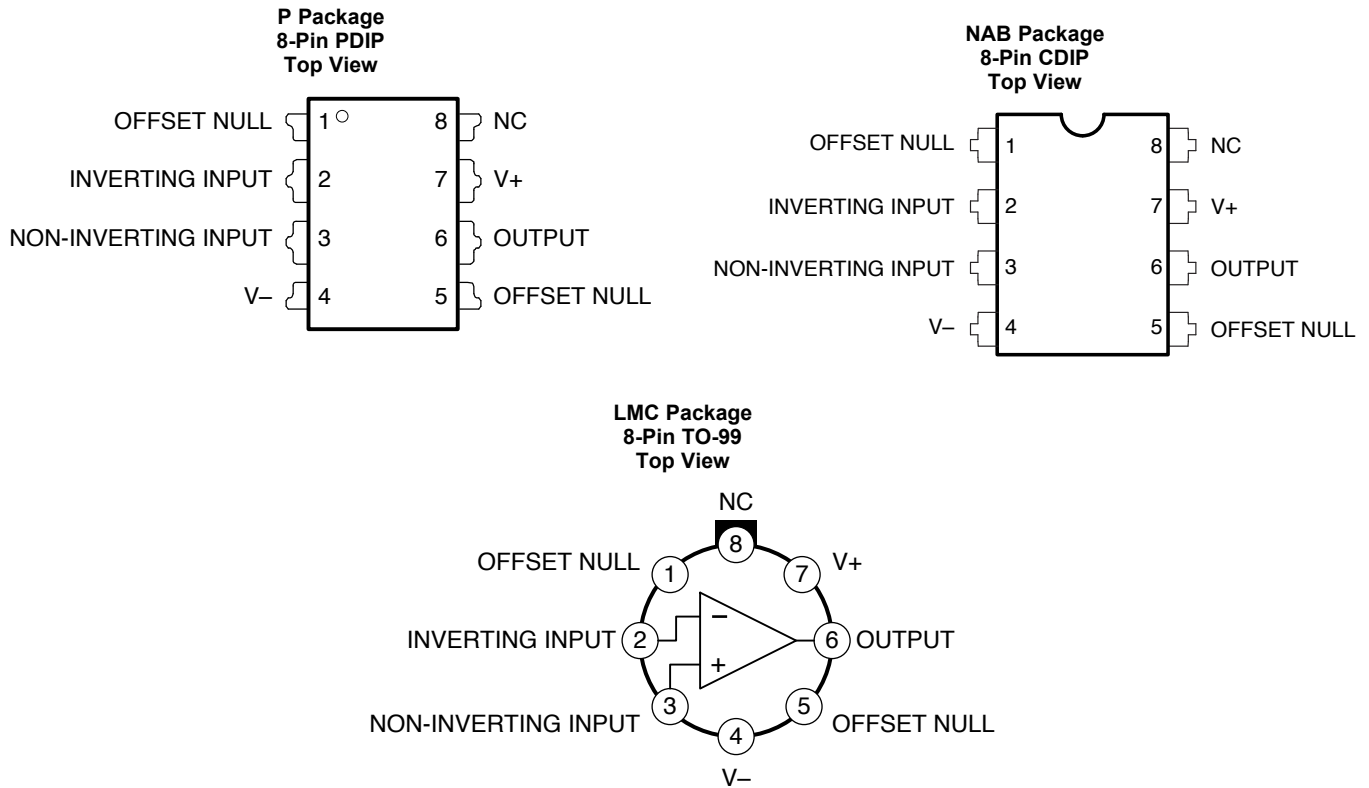
#### Simplified Application



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## 5 Pin Configuration and Functions



### Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
INVERTING INPUT	2	I	Inverting signal input
NC	8	N/A	No Connect, leave floating
NONINVERTING INPUT	3	I	Noninverting signal input
OFFSET NULL	1	I	Offset null pin used to eliminate the offset voltage and balance the input voltages.
OFFSET NULL	5		
OUTPUT	6	O	Amplified signal output
V+	7	I	Positive supply voltage
V-	4	I	Negative supply voltage

# S102S01/S102S02 S202S01/S202S02

## SIP Type SSR for Medium Power Control

### ■ Features

1. High radiation resin mold package
2. RMS ON-state current  
 $I_T$  : 8 Arms at  $T_C \leq 80^\circ\text{C}$   
 (With heat sink)
3. Built-in zero-cross circuit  
 (S102S02/S202S02)
4. High repetitive peak OFF-state voltage  
 S102S01/S102S02  $V_{\text{DRM}}$  : MIN. 400V  
 S202S01/S202S02  $V_{\text{DRM}}$  : MIN. 600V
5. Isolation voltage between input and output  
 ( $V_{\text{iso}}$  : 4 000V<sub>rms</sub>)
6. Approved by CSA, No. LR63705  
 Recognized by UL, file No. E94758

### ■ Applications

1. Automatic vending machines, programmable controllers
2. Amusement equipment

### ■ Model Line-ups

	For 100V lines	For 200V lines
For phase control No built-in zero-cross circuit	<b>S102S01</b>	<b>S202S01</b>
Built-in zero-cross circuit	<b>S102S02</b>	<b>S202S02</b>

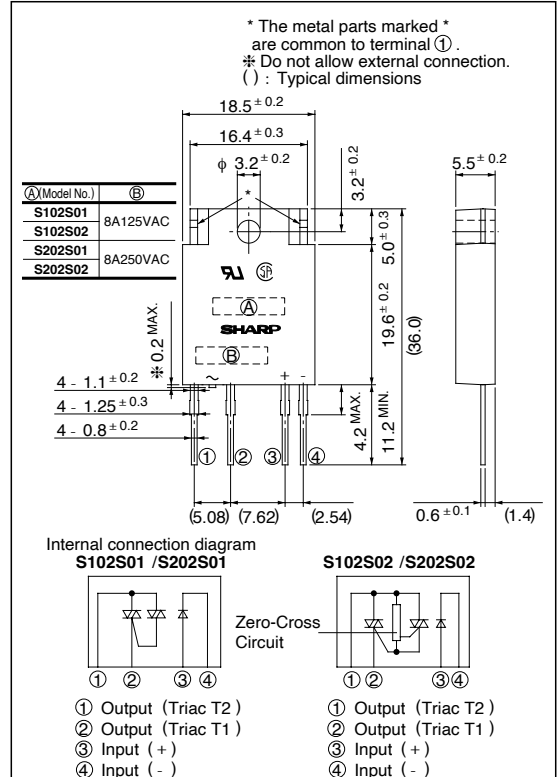
### ■ Absolute Maximum Ratings

( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Rating		Unit
		S102S01 S102S02	S202S01 S202S02	
Input	Forward current	50		mA
	Reverse voltage	6		V
	*1 RMS ON-state current	8		A <sub>rms</sub>
Output	*2 Peak one cycle surge current	80		A
	Repetitive peak OFF-state voltage	400	600	V
	Non-repetitive peak OFF-state voltage	400	600	V
	Critical rate of rise of ON-state current	50		A/ $\mu\text{s}$
	Operating frequency	45 to 65		Hz
	*3 Isolation voltage	4 000		V <sub>rms</sub>
Operating temperature		- 25 to + 100		°C
Storage temperature		- 30 to + 125		°C
*4 Soldering temperature		260		°C

### ■ Outline Dimensions

(Unit : mm)

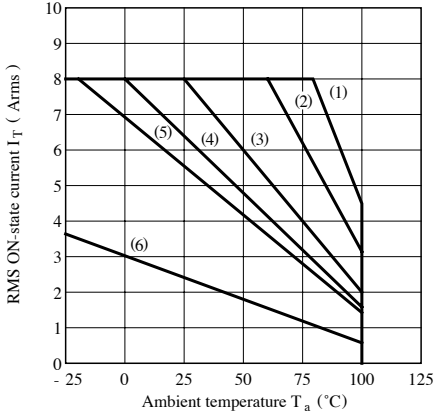


Electro-optical Characteristics

(Ta = 25°C)

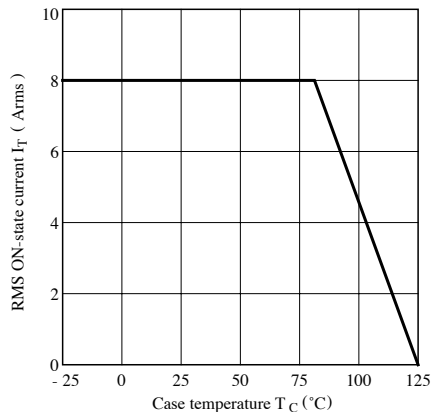
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	$V_F$	$I_F = 20\text{mA}$	-	1.2	1.4	V
	Reverse current	$I_R$	$V_R = 3\text{V}$	-	-	$10^{-4}$	A
Output	Repetitive peak OFF-state current	$I_{\text{DRM}}$	$V_D = V_{\text{DRM}}$	-	-	$10^{-4}$	A
	ON-state voltage	$V_T$	Resistance load $I_F = 20\text{mA}, I_T = 2\text{Arms}$	-	-	1.5	$V_{\text{rms}}$
	Holding current	$I_H$	-	-	-	50	mA
	Critical rate of rise of OFF-state voltage	$dV/dt$	$V_D = 2/3 \cdot V_{\text{DRM}}$	30	-	-	$\text{V}/\mu\text{s}$
	Critical rate of rise of commutating OFF-state voltage	$(dV/dt)_C$	$T_j = 125^\circ\text{C}, dI_T/dt = 4.0\text{A/ms}, V_D = 400\text{V}$	5	-	-	$\text{V}/\mu\text{s}$
	Zero-cross voltage	$V_{\text{OX}}$	$I_F = 8\text{mA}$	-	-	35	V
	Minimum trigger current	$I_{\text{FT}}$	$V_D = 12\text{V}, R_L = 30\Omega$	-	-	8	mA
Transfer characteristics			$V_D = 6\text{V}, R_L = 30\Omega$	-	-	8	mA
	Isolation resistance	$R_{\text{ISO}}$	DC500V, 40 to 60 % RH	$10^{10}$	-	-	$\Omega$
	Turn-on time	$t_{\text{on}}$	AC 50Hz	-	-	1	ms
				-	-	10	ms
	Turn-off time	$t_{\text{off}}$	-	-	-	10	ms
Thermal resistance (Between junction and case)		$R_{\text{th(j-c)}}$	-	-	4.5	-	$^\circ\text{C}/\text{W}$
Thermal resistance (Between junction and ambience)		$R_{\text{th(j-a)}}$	-	-	40	-	$^\circ\text{C}/\text{W}$

Fig. 1 RMS ON-state Current vs. Ambient Temperature

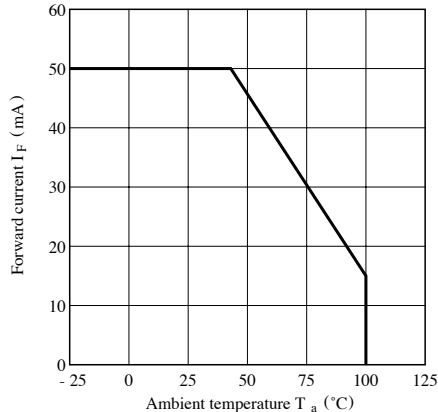


- (1) With infinite heat sink
- (2) With heat sink (200 x 200 x 2 mm Al plate)
- (3) With heat sink (100 x 100 x 2 mm Al plate)
- (4) With heat sink (75 x 75 x 2 mm Al plate)
- (5) With heat sink (50 x 50 x 2 mm Al plate)
- (6) Without heat sink
- (Note) With the Al heat sink set up vertically, tighten the device at the center of the Al heat sink with a torque of 0.4N • m and apply thermal conductive silicone grease on the heat sink mounting plate. Forcible cooling shall not be carried out.

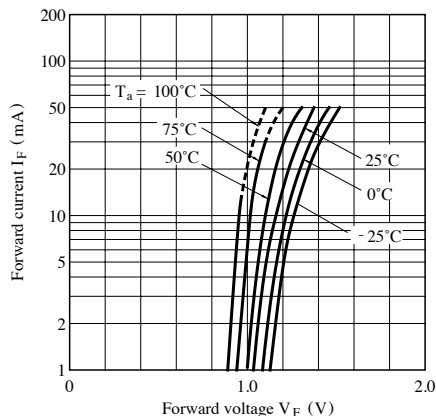
**Fig. 2 RMS ON-state Current vs. Case Temperature**



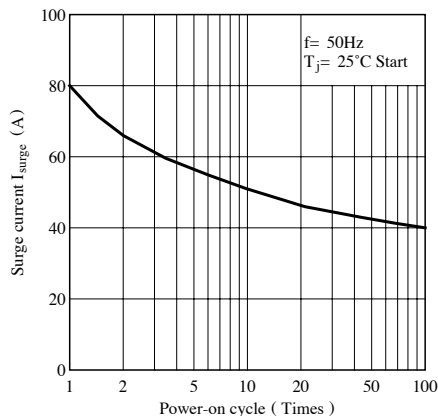
**Fig. 3 Forward Current vs. Ambient Temperature**



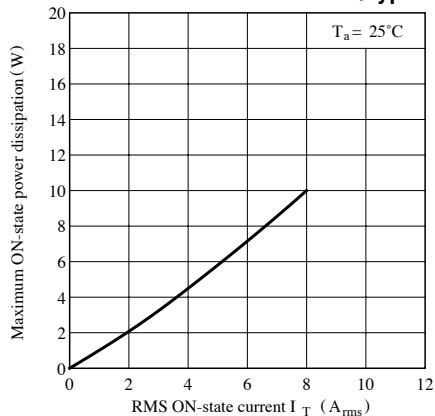
**Fig. 4 Forward Current vs. Forward Voltage**



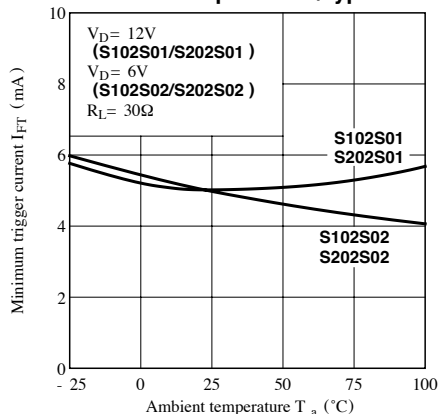
**Fig. 5 Surge Current vs. Power-on Cycle**



**Fig. 6 Maximum ON-state Power Dissipation vs. RMS ON-state Current (Typical Value)**

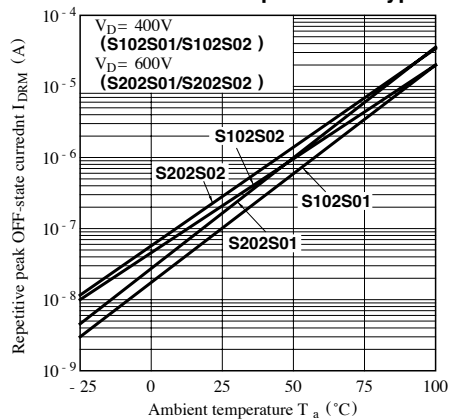


**Fig. 7 Minimum Trigger Current vs. Ambient Temperature (Typical Value)**





**Fig. 8 Repetitive Peak OFF-state Current  
vs. Ambient Temperature (Typical Value)**



● Please refer to the chapter “Precautions for Use”

## PIEZO PASSIVE BUZZER - VERTICAL

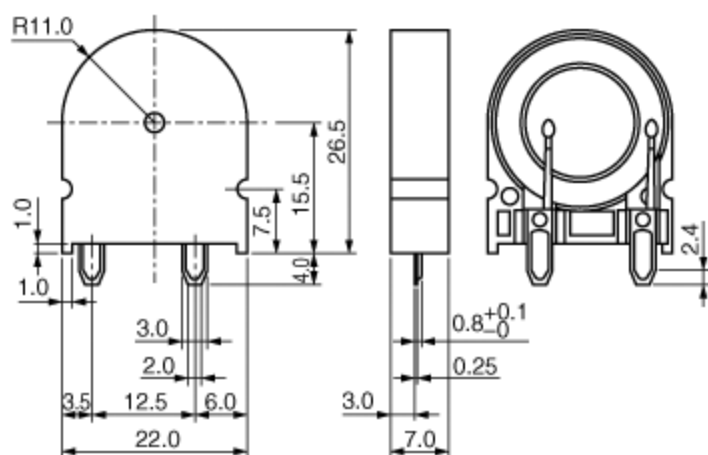
Externally driven piezoelectric sounders are used in washing machines, keyboard, timer, digital watches, electronic calculators, telephones and other consumer equipment. They are driven by a signal (ex.: 2048Hz or 4096Hz) from an LSI/MCU and provide melodious sound. Also, if the source is like a melody IC, you can also sound melody. Equivalent to Murata PKM22EPHT2001-B0.

### Features

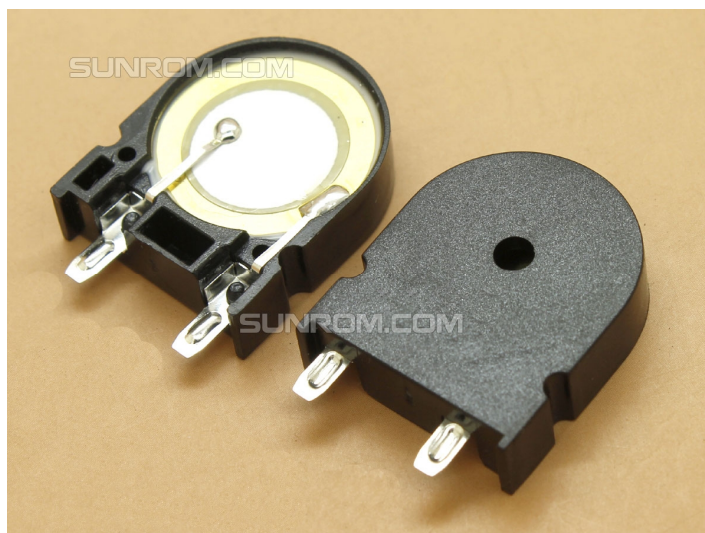
1. Low power consumption
2. No noise and high reliability
3. No electric noise and little influence on peripheral circuits
4. It complies with the JEITA standard (RC - 8180A)

### DIMENSIONS

PCB Holes we suggest of 3.2mm dia. with 12.5mm space apart



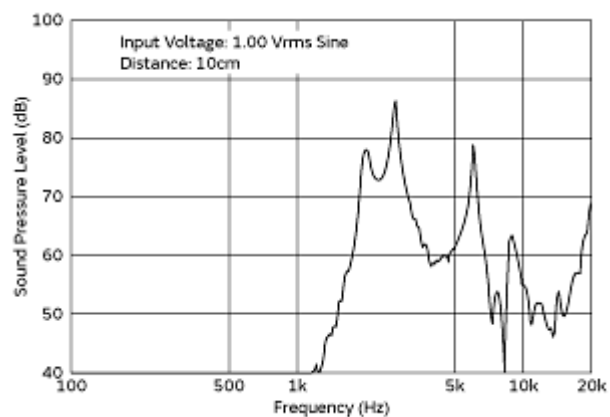
Tol.:  $\pm 0.5$   
(in mm)



### SPECIFICATIONS

Size	22.0×7.0×26.5 mm
Frequency	2 kHz
Sound Pressure Level	70dB (min.)
Measure Condition of Sound Pressure Level	[3.0Vp-p,2.0kHz,square wave,10cm]
Capacitance	19nF
Capacitance Tolerance	±30%
Measurement Condition of Capacitance	[120Hz]
Maximum input voltage	±12.5Vo-p max. or 25.0Vo-p max
Operating Temperature Range	-20°C to 70°C
Storage Temperature Range	-40°C to 80°C
Shape	Lead
Lead Shape	Pin Type
Lead length	Lead length:4.0mm
Drive Type	External Drive
EIAJ Part Number	PS-RP2-V27-20

### Figure 1 Frequency Characteristics (sine wave)



### Figure 2 Frequency Characteristics (square wave)

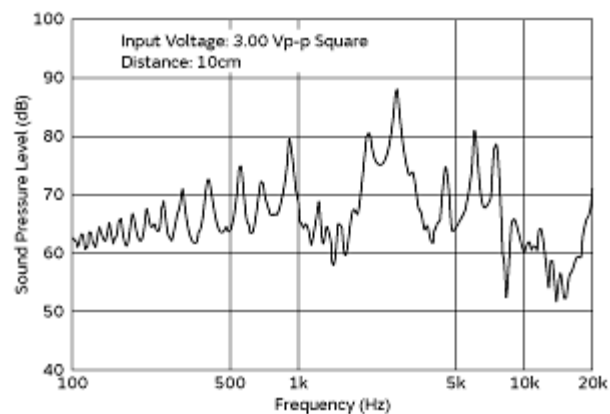
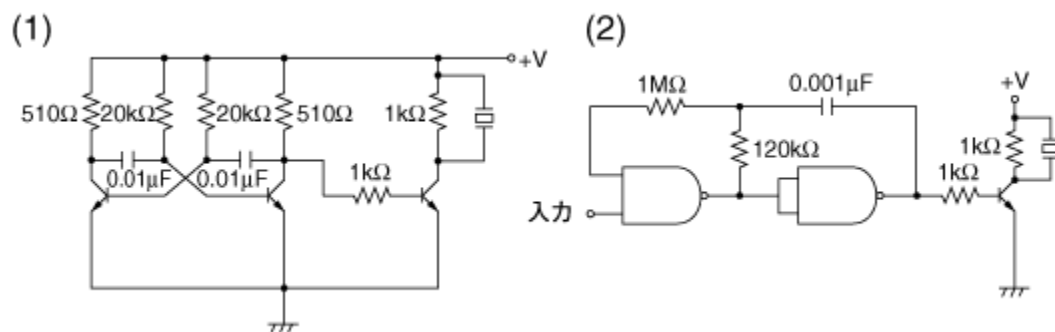


Figure 3 Typical Externally Driving circuit, Astable, NAND, Inverter gates



## NOTES

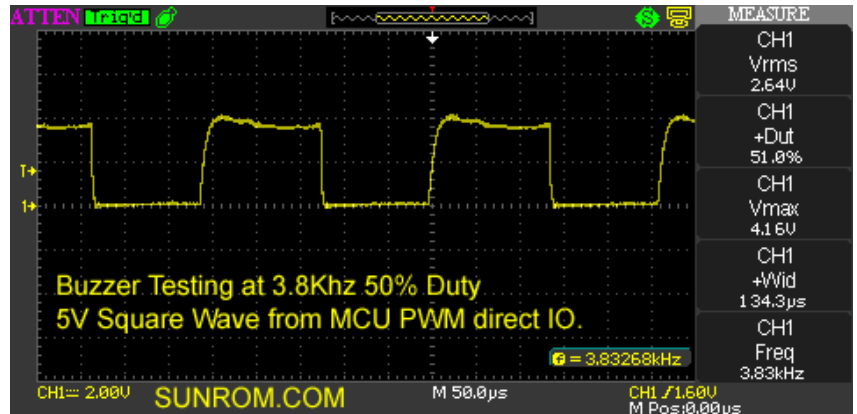
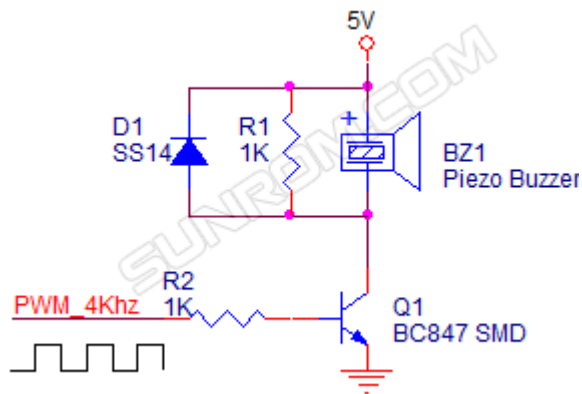
Please note, Unlike electromagnetic types which has coil, This buzzer does not contains internal driving circuit, so do not expect to just power on and hear something. It needs square wave of 4Khz to drive. The black case provides cavity for resonance and protection. You can vary its frequency to create tones just like you hear from microwave or washing machine.

When compared to low cost electromagnetic type buzzer this piezo consumes only 2-3mA, while coil type can take upto 100mA. Low current consumption makes it ideal for battery operation. While electromagnetic type is high on EMI, this piezo's emi noise is very negligible.

### Buzzer Comparison

Parameter	Piezo Buzzer This model	Other Electromagnetic Coil Type
Current	2-3mA	150-200mA
Moisture	Proof	Sensitive to moisture
Operation Life	Long, No moving parts	Coil heats and life is around 2 years
Operation Temp	High upto 150 deg C	approx 50 deg C
Noise	Does not emit	Emit high EMI noise over driving voltage
Technology	Piezo Vibration	Coil Oscillation
Frequency	Variable 1-10Khz	Fixed

You can use frequency from 1 KHz to 10 KHz but highest amplitude you will get around 4 KHz. Please see graph of frequency response above. This is how we use it in our designs at Sunrom.



## ORDERING DETAILS

Sunrom Part#	Ordering Page
5288	<a href="http://www.sunrom.com/m/5288">http://www.sunrom.com/m/5288</a>